

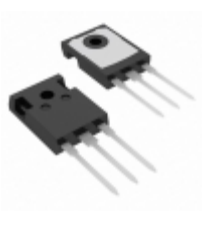
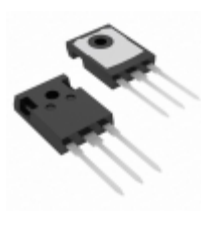

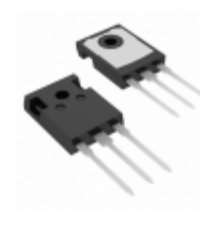
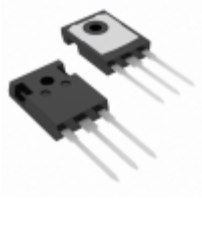
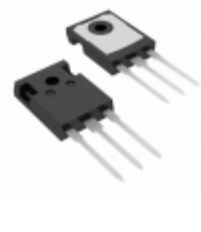
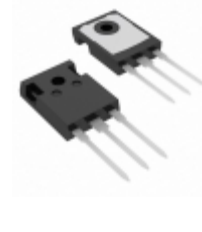
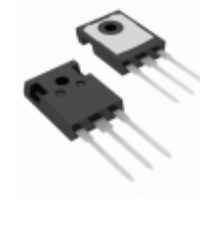
	<h2 style="color: red;">FDH50N50</h2>	
	Hersteller-Teilenummer:	FDH50N50
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 500V 48A TO-247
Datenblätter:	 FDH50N50.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 30198 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	FDH50N50
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 500V 48A TO-247
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	30198 pcs Stock
detaillierte Beschreibung	N-Channel 500V 48A (Tc) 625W (Tc) Through Hole
Serie	UniFET™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Verlustleistung (max)	625W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	48A (Tc)
Rds On (Max) @ Id, Vgs	105 mOhm @ 24A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	137nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	6460pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FDH50N50 ist neu im Original, Suche FDH50N50 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDH50N50 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FDH50N50: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FDH44N50 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 44A TO-247</p>	 <p>FDH5500 Fairchild/ON Semiconductor MOSFET N-CH 55V 75A TO-247</p>	 <p>FDH45N50F_F133 Fairchild/ON Semiconductor MOSFET N-CH 500V 45A TO-247</p>	 <p>FDH45N50F-F133 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 45A TO-247</p>
 <p>FDH5500 AMI Semiconductor / ON Semiconductor MOSFET N-CH 55V 75A TO-247</p>	 <p>FDH44N50 Fairchild/ON Semiconductor MOSFET N-CH 500V 44A TO-247</p>	 <p>FDH50N50 Fairchild/ON Semiconductor MOSFET N-CH 500V 48A TO-247</p>	 <p>FDH50N50-F133 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 48A TO-247</p>

heiße Teile

Mehr

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FDH047AN08A0	FDH047AN08A0	FDH047AN08A0	FDH055N15A	FDH055N15A
FDH15N50	FDH15N50	FDH210AN08	FDH210N08	FDH210N08
FDH27N50	FDH27N50	FDH300A.TR	FDH3369C	FDH44N50
FDH44N50	FDH45N50F	FDH50N50	FDH50N50_F133	FDH5500_F085
GCM0335C1E470JD03D	IR3E3024/E2	ISL8490IP	KL32TE120J	KS621K30HB
LT3837EFE#PBF	N330CH06	PEEL18CV8J	PHP96NQ03LT	PI3B3125WX
PS2711-1L	RB055LA-40	RDD022N60	SI3010KM	SMM3Z5V1RT1G
SUM120N04-1M7L-GE3	TA20192004DW	TPS76330DBVT	VI-J02-05 25W	WPC10R24S08F

Contact us:Info@Y-IC.com

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